

EE3901 IDEAL DIODE EQUATION DERIVATION

Minority carrier diffusion equations (valid in quasineutral region where E field ≈ 0)

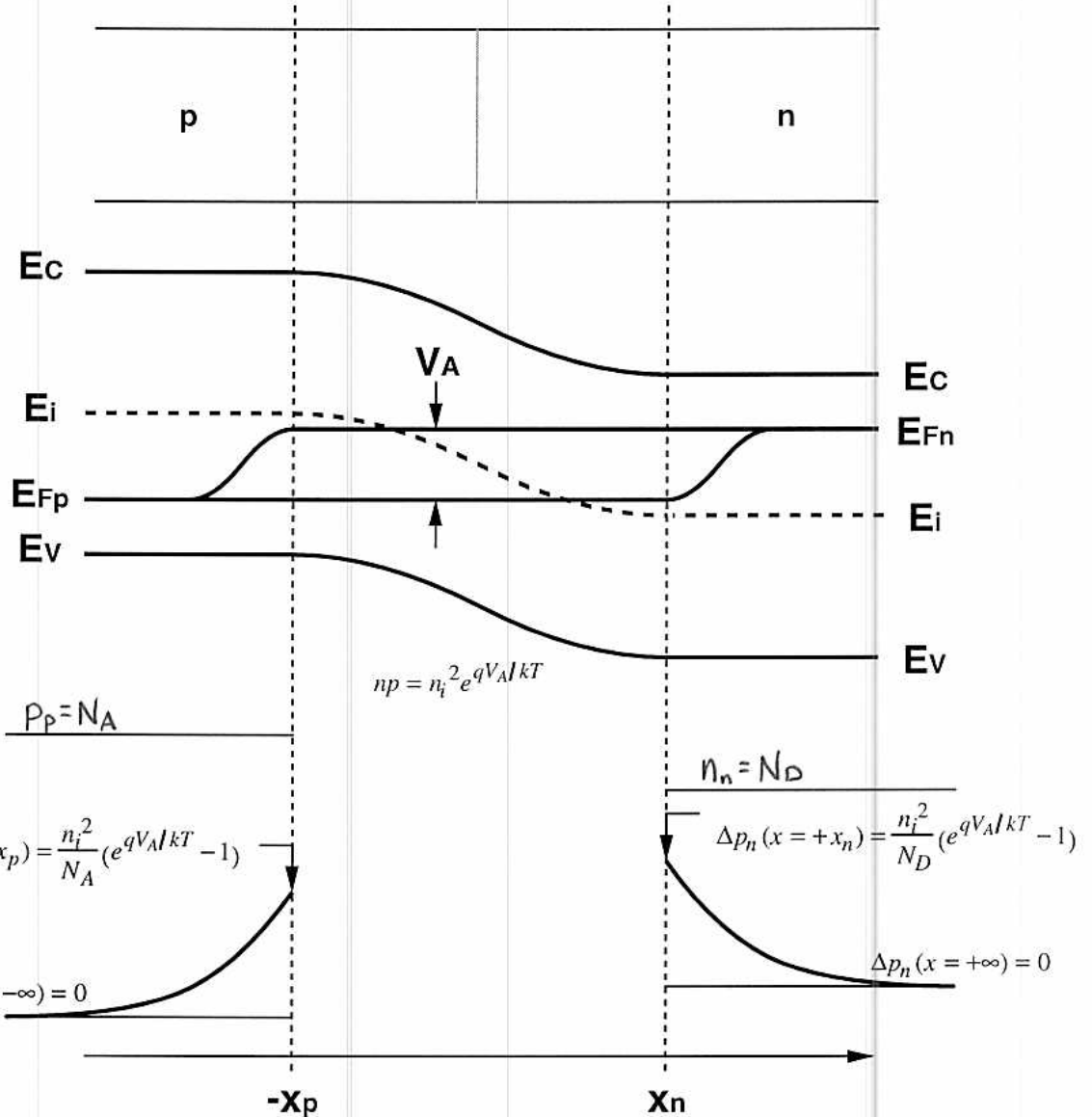
$$\frac{\partial \Delta n_p}{\partial t} = D_N \frac{\partial^2 \Delta n_p}{\partial x^2} - \frac{\Delta n_p}{\tau_N}$$

$$\frac{\partial \Delta p_n}{\partial t} = D_P \frac{\partial^2 \Delta p_n}{\partial x^2} - \frac{\Delta p_n}{\tau_P}$$

Steady state (DC voltage, current: all $d/dt = 0$)

$$0 = D_N \frac{d^2 \Delta n_p}{dx^2} - \frac{\Delta n_p}{\tau_N}$$

$$0 = D_P \frac{d^2 \Delta p_n}{dx^2} - \frac{\Delta p_n}{\tau_P}$$



"LAW OF THE JUNCTION" at edges of depletion region (assumes quasiFermi levels flat through depletion region)

Boundary conditions at edges of depletion region (from law of the junction)

$$\Delta n_p(x = -x_p) = \frac{n_i^2}{N_A} (e^{qV_A/kT} - 1)$$

Boundary conditions far from depletion region (returns to equilibrium conc)

$$\Delta n_p(x = -\infty) = 0$$

Solutions to differential equation subject to boundary conditions

$$\Delta n_p = \frac{n_i^2}{N_A} (e^{qV_A/kT} - 1) e^{(x+x_p)/L_N} \quad (x \leq -x_p)$$

$$\Delta p_n = \frac{n_i^2}{N_D} (e^{qV_A/kT} - 1) e^{-(x-x_n)/L_P} \quad (x \geq +x_n)$$

Current density equation

$$J_N = qD_N \frac{d\Delta n_p}{dx}$$

$$J_P = -qD_P \frac{d\Delta p_n}{dx}$$

Plug differential equation solution into current density equation

$$J_N = q \frac{D_N}{L_N} \frac{n_i^2}{N_A} (e^{qV_A/kT} - 1) e^{(x+x_p)/L_N} \quad (x \leq -x_p)$$

$$J_P = q \frac{D_P}{L_P} \frac{n_i^2}{N_D} (e^{qV_A/kT} - 1) e^{-(x-x_n)/L_P} \quad (x \geq +x_n)$$

Current density equation

$$J_N = qD_N \frac{d\Delta n_p}{dx}$$

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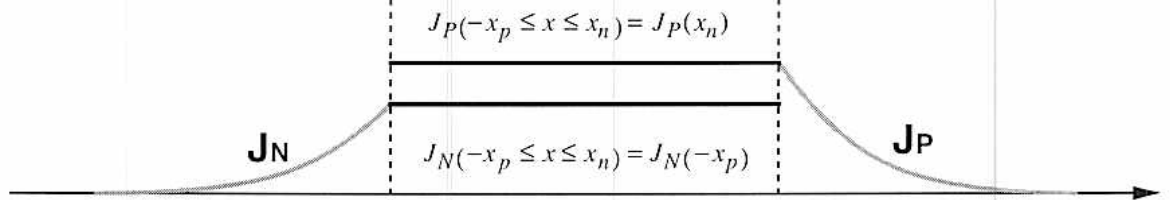
$$J_N = q \frac{D_N}{L_N} \frac{n_i^2}{N_A} (e^{qV_A/kT} - 1) e^{(x+x_p)/L_N} \quad (x \leq -x_p)$$

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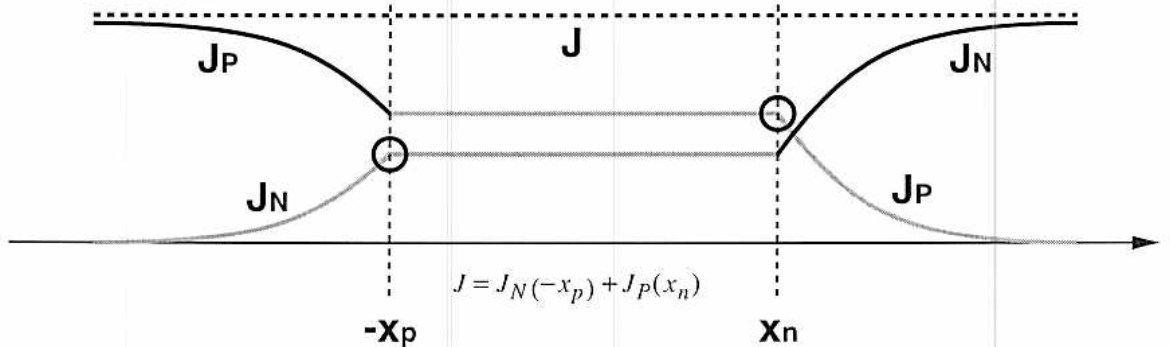
Plug differential equation solution into current density equation



Assume no R-G in depletion region



Steady state: total J constant throughout



J given by sum of hole, electron components at edges of depletion region

$$J_N(-x_p) = q \frac{D_N}{L_N} \frac{n_i^2}{N_A} (e^{qV_A/kT} - 1)$$

$$J_P(x_n) = q \frac{D_P}{L_P} \frac{n_i^2}{N_D} (e^{qV_A/kT} - 1)$$

Evaluate current density expressions at edges of depletion region

Total current density

$$J = q \left[\frac{D_N}{L_N} \frac{n_i^2}{N_A} + \frac{D_P}{L_P} \frac{n_i^2}{N_D} \right] (e^{qV_A/kT} - 1)$$

Total current $I = JA$
Current density x junction area A

$$I = qA \left[\frac{D_N}{L_N} \frac{n_i^2}{N_A} + \frac{D_P}{L_P} \frac{n_i^2}{N_D} \right] (e^{qV_A/kT} - 1)$$